

Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
L1	22	((("20030080842") or ("20020170491") or ("20020069818") or ("20020059901") or ("20020049129") or ("20020038627") or ("20020023581") or ("6562130") or ("6534026") or ("6508880") or ("6428621") or ("6297522") or ("6100111") or ("6034001") or ("5679153") or ("5571374") or ("5227034") or ("4981551") or ("4964547") or ("4912064") or ("4912063") or ("4865685"))).PN.	US-PGPUB; USPAT; USOCR	OR	OFF	2005/02/22 13:23
L3	12549	((438/478,507,692,693,719,753,931) or (216/38,67,83,88,90,99) or (451/41) or (134/1.2,1.3) or (117/951)).CCLS.	US-PGPUB; USPAT; USOCR	OR	OFF	2005/02/22 13:49
L4	7534	(SIC OR (silicon ADJ carbide)) AND (epitax\$4 OR homo\$1epitax\$4)	US-PGPUB; USPAT; USOCR	OR	OFF	2005/02/22 13:50
L5	2963	L4 AND transistor	US-PGPUB; USPAT; USOCR	OR	OFF	2005/02/22 13:50
L6	151	L5 AND ((KOH OR (potassium ADJ hydroxide)) SAME etch\$4)	US-PGPUB; USPAT; USOCR	OR	OFF	2005/02/22 13:50
L7	80	L6 AND ((plasma\$4 OR (reactive ADJ ion)) WITH etch\$4)	US-PGPUB; USPAT; USOCR	OR	OFF	2005/02/22 13:50
L8	3	L3 AND L7	US-PGPUB; USPAT; USOCR	OR	OFF	2005/02/22 13:50
S1	22	((("20030080842") or ("20020170491") or ("20020069818") or ("20020059901") or ("20020049129") or ("20020038627") or ("20020023581") or ("6562130") or ("6534026") or ("6508880") or ("6428621") or ("6297522") or ("6100111") or ("6034001") or ("5679153") or ("5571374") or ("5227034") or ("4981551") or ("4964547") or ("4912064") or ("4912063") or ("4865685"))).PN.	US-PGPUB; USPAT; USOCR	OR	OFF	2005/02/17 08:56

S2	22	((("20030080842") or ("20020170491") or ("20020069818") or ("20020059901") or ("20020049129") or ("20020038627") or ("20020023581") or ("6562130") or ("6534026") or ("6508880") or ("6428621") or ("6297522") or ("6100111") or ("6034001") or ("5679153") or ("5571374") or ("5227034") or ("4981551") or ("4964547") or ("4912064") or ("4912063") or ("4865685")).PN.	US-PGPUB; USPAT; USOCR	OR	OFF	2005/02/17 09:02
S3	5	S2 AND ((etch\$4 WITH (SiC OR (silicon ADJ carbide))) AND epitax\$4 AND polish\$4)	US-PGPUB; USPAT; USOCR	OR	OFF	2005/02/22 13:46
S4	323	((etch\$4 WITH (SiC OR (silicon ADJ carbide))) AND epitax\$4 AND polish\$4)	US-PGPUB; USPAT; USOCR	OR	OFF	2005/02/17 14:32
S5	51	S4 AND (KOH OR (potassium ADJ hydroxide))	US-PGPUB; USPAT; USOCR	OR	OFF	2005/02/17 09:20
S6	44	S4 AND ((KOH OR (potassium ADJ hydroxide)) SAME etch\$4)	US-PGPUB; USPAT; USOCR	OR	OFF	2005/02/18 16:16
S7	8	S6 AND boule	US-PGPUB; USPAT; USOCR	OR	OFF	2005/02/17 10:04
S8	1	("4866005").PN.	USPAT; USOCR	OR	OFF	2005/02/17 10:04
S9	1	("5,679,153").PN.	USPAT; USOCR	OR	OFF	2005/02/17 11:03
S10	197	S4 AND ((plasma\$4 OR (reactive ADJ ion)) WITH etch\$4)	US-PGPUB; USPAT; USOCR	OR	OFF	2005/02/18 16:16
S11	130	S10 AND ((reactive ADJ ion) WITH etch\$4)	US-PGPUB; USPAT; USOCR	OR	OFF	2005/02/17 14:21
S12	26	S11 AND ((KOH OR (potassium ADJ hydroxide)) SAME etch\$4)	US-PGPUB; USPAT; USOCR	OR	OFF	2005/02/17 14:21
S13	324	((etch\$4 WITH (SiC OR (silicon ADJ carbide))) AND (epitax\$4 OR homo\$1epitax\$4) AND polish\$4)	US-PGPUB; USPAT; USOCR	OR	OFF	2005/02/17 14:33
S14	17	S13 AND ((defect\$4 OR dis\$1locat\$4) WITH thick)	US-PGPUB; USPAT; USOCR	OR	OFF	2005/02/17 16:33

S15	324	((etch\$4 WITH (SiC OR (silicon ADJ carbide))) AND (epitax\$4 OR homo\$1epitax\$4) AND polish\$4)	US-PGPUB; USPAT; USOCR	OR	OFF	2005/02/18 16:15
S16	3	S15 AND ((defect\$4 OR dis\$1locat\$4) WITH (KOH OR (potassium ADJ hydroxide)))	US-PGPUB; USPAT; USOCR	OR	OFF	2005/02/17 16:34
S17	324	((etch\$4 WITH (SiC OR (silicon ADJ carbide))) AND (epitax\$4 OR homo\$1epitax\$4) AND polish\$4)	US-PGPUB; USPAT; USOCR	OR	OFF	2005/02/18 16:08
S18	19	S17 AND (thread\$4 WITH dis\$1location\$4)	US-PGPUB; USPAT; USOCR	OR	OFF	2005/02/18 16:10
S19	7521	(SiC OR (silicon ADJ carbide)) AND (epitax\$4 OR homo\$1epitax\$4)	US-PGPUB; USPAT; USOCR	OR	OFF	2005/02/18 16:15
S20	2960	S19 AND transistor	US-PGPUB; USPAT; USOCR	OR	OFF	2005/02/18 16:16
S21	151	S20 AND ((KOH OR (potassium ADJ hydroxide)) SAME etch\$4)	US-PGPUB; USPAT; USOCR	OR	OFF	2005/02/18 16:16
S22	80	S21 AND ((plasma\$4 OR (reactive ADJ ion)) WITH etch\$4)	US-PGPUB; USPAT; USOCR	OR	OFF	2005/02/22 09:26
S23	7534	(SiC OR (silicon ADJ carbide)) AND (epitax\$4 OR homo\$1epitax\$4)	US-PGPUB; USPAT; USOCR	OR	OFF	2005/02/22 09:26
S24	2963	S23 AND transistor	US-PGPUB; USPAT; USOCR	OR	OFF	2005/02/22 09:26
S25	151	S24 AND ((KOH OR (potassium ADJ hydroxide)) SAME etch\$4)	US-PGPUB; USPAT; USOCR	OR	OFF	2005/02/22 09:26
S26	80	S25 AND ((plasma\$4 OR (reactive ADJ ion)) WITH etch\$4)	US-PGPUB; USPAT; USOCR	OR	OFF	2005/02/22 09:26
S27	19	S26 AND (bi\$1polar WITH transistor)	US-PGPUB; USPAT; USOCR	OR	OFF	2005/02/22 09:27